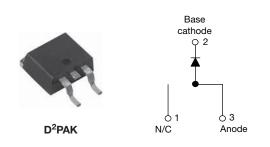


VS-MBRB1035-M3, VS-MBRB1045-M3

Vishay Semiconductors

High Performance Schottky Rectifier, 10 A



PRODUCT SUMMARY								
I _{F(AV)}	10 A							
V _R	35 V, 45 V							
V _F at I _F	0.57 V							
I _{RM}	15 mA at 125 °C							
T _J max.	150 °C							
E _{AS}	8 mJ							
Package	TO-263AB (D ² PAK)							
Diode variation	Single die							

FEATURES

- 150 °C T_J operation
- TO-220 and D²PAK packages
- Low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
 RoHS compliant HALOGEN
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Designed and qualified according to JEDEC[®]-JESD 47
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

This Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS VALUES								
I _{F(AV)}	Rectangular waveform	10	^						
I _{FRM}	T _C = 135 °C	20	— A						
V _{RRM}		35/45	V						
I _{FSM}	t _p = 5 μs sine	1060	A						
V _F	10 A _{pk} , T _J = 125 °C	0.57	V						
TJ	Range	- 65 to 150	C°						

VOLTAGE RATINGS									
PARAMETER	SYMBOL	VS-MBRB1035-M3	VS-MBRB1045-M3	UNITS					
Maximum DC reverse voltage	ximum DC reverse voltage V _R		45	V					
Maximum working peak reverse voltage	V _{RWM}	35	45	v					

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST CON	TEST CONDITIONS						
Maximum average forward current	I _{F(AV)}	T_{C} = 135 °C, rated V_{R}	$T_{\rm C}$ = 135 °C, rated V _R						
Peak repetitive forward current	I _{FRM}	Rated V _R , square wave, 20 kl	Rated V _R , square wave, 20 kHz, T _C = 135 °C						
Non-repetitive surge current	I _{FSM}	5 µs sine or 3 µs rect. pulse	1060	А					
		Surge applied at rated load c single phase, 60 Hz	150						
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 2 A, L = 4 m	8	mJ					
Repetitive avalanche current	I _{AR}	Current decaying linearly to z Frequency limited by T _J maxi	2	А					

Revision: 28-Feb-14

Document Number: 94947

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>

1



Vishay Semiconductors

ELECTRICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS						
		20 A	T _J = 25 °C	0.84					
Maximum forward voltage drop	V _{FM} ⁽¹⁾	10 A	T.I = 125 °C	0.57	V				
		20 A	$1_{\rm J} = 125$ C	0.72					
Maximum instantaneous reverse	I _{BM} ⁽¹⁾	T _J = 25 °C	Rated DC voltage	0.1	m۸				
current	IRM \''	T _J = 125 °C	haled DC vollage	15	mA				
Threshold voltage	V _{F(TO)}	$T_{i} = T_{i}$ maximum		0.354	V				
Forward slope resistance	r _t	ij = ijmaximum		17.6	mΩ				
Maximum junction capacitance	CT	$V_R = 5 V_{DC}$ (test signal range	$V_{R} = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C						
Typical series inductance	L _S	Measured from top of ter	8.0	nH					
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs					

Note

 $^{(1)}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER		SYMBOL	SYMBOL TEST CONDITIONS		UNITS				
Maximum junction temperature range		TJ		- 65 to 150	°C				
Maximum storage temperat	ure range	T _{Stg}		- 65 to 175	U				
Maximum thermal resistance, junction to case		R _{thJC}	DC operation	2.0	°C/W				
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased (Only for TO-220) 0.50		0/11				
Approvimente weight				2	g				
Approximate weight				0.07	oz.				
Mounting torque minimum maximum				6 (5)	kgf · cm				
				12 (10)	(lbf · in)				
			Case style D ² PAK	MBRE	31035				
Marking device			Case signe D-PAR	MBRE	31045				

VS-MBRB1035-M3, VS-MBRB1045-M3



Vishay Semiconductors

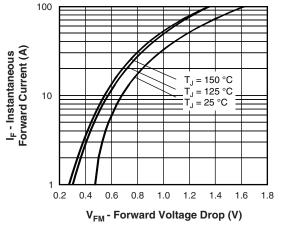
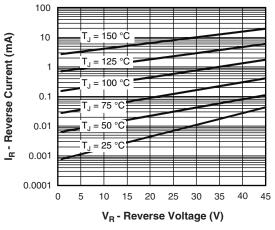
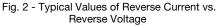


Fig. 1 - Maximum Forward Voltage Drop Characteristics





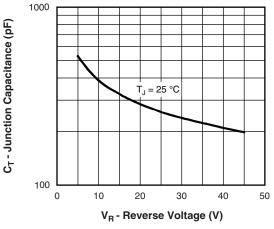


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

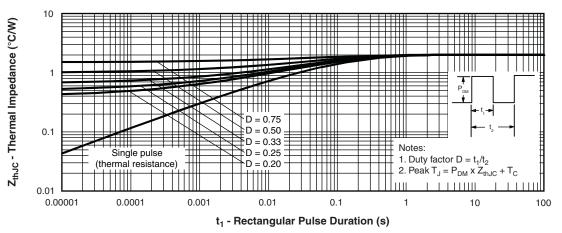
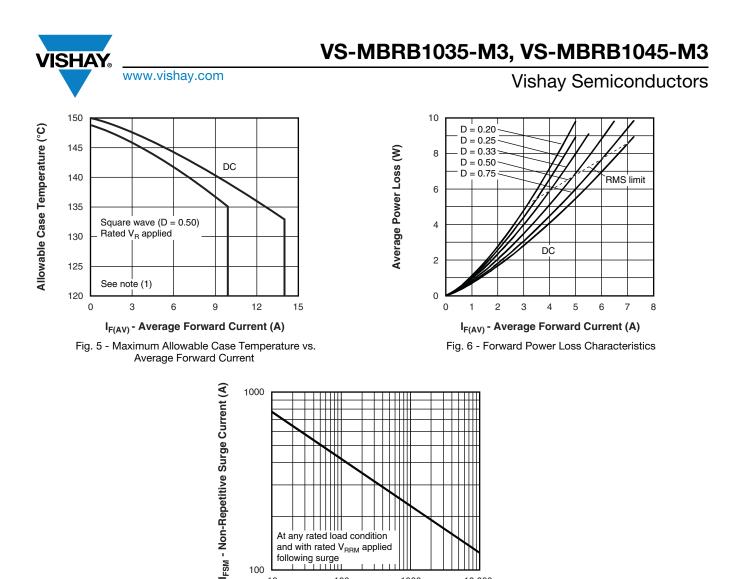


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

Revision: 28-Feb-14

3

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



At any rated load condition and with rated $\mathrm{V}_{\mathrm{RRM}}$ applied

100

 t_p - Square Wave Pulse Duration (µs) Fig. 7 - Maximum Non-Repetitive Surge Current

1000

10 000

following surge

100 10

Note

Revision: 28-Feb-14 Document Number: 94947 4 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishav.com/doc?91000



VS-MBRB1035-M3, VS-MBRB1045-M3

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code	VS-	MBR	В	10	45	TRL	-M3
		2	3	4	5	6	7
	H		hay Sen		•	oduct	
			ential pa Surface				
	님		rent rati tage rati	•	= 10 A)		= 35 V = 45 V
	6		one = T RL = Ta		reel (left		
	_	• TI	RR = Ta	pe and	reel (rig	ht orien	ted)
	7	M3	3 = Halo	gen-free	e, RoHS	S-compli	iant and

ORDERING INFORMATION										
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION							
VS-MBRB1035-M3	50	1000	Antistatic plastic tubes							
VS-MBRB1035TRR-M3	800	800	13" diameter reel							
VS-MBRB1035TRL-M3	800	800	13" diameter reel							
VS-MBRB1045-M3	50	1000	Antistatic plastic tubes							
VS-MBRB1045TRR-M3	800	800	13" diameter reel							
VS-MBRB1045TRL-M3	800	800	13" diameter reel							

LINKS TO RELATED DOCUMENTS								
Dimensions	www.vishay.com/doc?95046							
Part marking information	www.vishay.com/doc?95054							
Packaging information	www.vishay.com/doc?95032							
SPICE model	www.vishay.com/doc?95293							

Outline Dimensions



D²PAK

DIMENSIONS in millimeters and inches

www.vishay.com

SHA



SYMBOL	MILLIMETERS		INCHES		NOTES	NOTES		MILLIM	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
A	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Datum A and B to be determined at datum plane H

⁽⁶⁾ Controlling dimension: inch

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-263AB

Revision: 08-Jul-15

1



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.